

a transceiver circuit device located on said front side;

said infrared detecting device further comprising a front side and a back side, said infrared detecting device back side aligned to face said front side of said circuit structure; and

said infrared emitting device further comprising a back side, said infrared emitting device back side aligned to face said infrared detecting device front side, whereby said infrared emitting device and said infrared detection device form an integrated infrared emitting and infrared detection device.

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